

Product Summary

PPAP and is ideal for use in:

DC-DC converters

Engine management systems

Body control electronics

| BV _{DSS} | R _{DS(ON)} max | l⊳ max T _C = +25°C |
|-------------------|-------------------------------|----------------------------------|
| co)/ | 11mΩ @ V _{GS} = 10V | 47.6A |
| 60V | 16mΩ @ V _{GS} = 4.5V | 39.5A |

This MOSFET is designed to meet the stringent requirements of

automotive applications. It is qualified to AEC-Q101, supported by a

Features and Benefits

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH6010LPDQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)



Description and Applications



Ordering Information (Note 4)

| Part Number | Packago | Packing | | |
|-----------------|------------------------|---------|-------------|--|
| Part Number | Package | Qty. | Carrier | |
| DMTH6010LPDQ-13 | PowerDI5060-8 (Type C) | 2,500 | Tape & Reel | |

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



)::= Manufacturer's Marking
H6010LD = Product Type Marking Code
YYWW = Date Code Marking
YY = Year (ex: 24 = 2024)
WW = Week (01 to 53)

100% Unclamped Ind



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | | Symbol | Value | Unit |
|--|-----------------|---|--------|--------------|------|
| Drain-Source Voltage | | | Vdss | 60 | V |
| Gate-Source Voltage | | | Vgss | ±20 | V |
| Continuous Drain Current (Note 6) $T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$ | | | ID | 47.6 33.7 | A |
| Continuous Drain Current (Note 5) | Steady State | $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$ | ID | 13.1 10.9 | А |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%) | Ідм | 170 | А | | |
| Maximum Continuous Body Diode Forward Current (Note 6) | | | ls | 31 | А |
| Avalanche Current, L = 0.1mH | | | las | 20 | А |
| Avalanche Energy, L = 0.1mH | | | Eas | 20 | mJ |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit | |
|---|------------------------|-------------|------|------|
| Total Power Dissipation (Note 5) | T _A = +25°C | PD | 2.8 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | Steady State | Reja | 53 | °C/W |
| Total Power Dissipation (Note 6) T _C = +25°C | | PD | 37.5 | W |
| Thermal Resistance, Junction to Case (Note 6) | Rejc | 4 | °C/W | |
| Operating and Storage Temperature Range | TJ, TSTG | -55 to +175 | °C | |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|--------------------|-----|------|------|------|--|--|
| OFF CHARACTERISTICS (Note 7) | 0, | | - 76 | | • | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 60 | | — | V | $V_{GS} = 0V, I_D = 1mA$ | |
| Zero Gate Voltage Drain Current | IDSS | _ | | 1 | μA | V _{DS} = 48V, V _{GS} = 0V | |
| Gate-Source Leakage | IGSS | | | ±100 | nA | $V_{GS} = \pm 20V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 7) | | | | | | | |
| Gate Threshold Voltage | Vgs(th) | 1 | _ | 3 | V | $V_{DS} = V_{GS}$, $I_D = 250 \mu A$ | |
| Static Drain-Source On-Resistance | Descent | _ | 8.5 | 11 | m0 | VGS = 10V, ID = 20A | |
| Static Drain-Source On-Resistance | Rds(on) | | 10.9 | 16 | mΩ | V _{GS} = 4.5V, I _D = 20A | |
| Diode Forward Voltage | Vsd | | 0.9 | 1.2 | V | V _{GS} = 0V, I _S = 20A | |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | • | • | • | |
| Input Capacitance | Ciss | — | 2615 | _ | pF | | |
| Output Capacitance | Coss | — | 1415 | - | pF | └ V _{DS} = 30V, V _{GS} = 0V, └ f = 1MHz | |
| Reverse Transfer Capacitance | Crss | _ | 58 | — | pF | | |
| Gate Resistance | Rg | _ | 0.67 | _ | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$ | |
| Total Gate Charge (V _{GS} = 4.5V) | Qg | _ | 20.3 | — | nC | | |
| Total Gate Charge (V _{GS} = 10V) | Qg | | 40.2 | — | nC | | |
| Gate-Source Charge | Qgs | _ | 5.9 | _ | nC | $V_{DS} = 30V, I_{D} = 20A$ | |
| Gate-Drain Charge | Qgd | _ | 9.3 | _ | nC | 1 | |
| Turn-On Delay Time | t _{D(ON)} | _ | 5.7 | _ | ns | $V_{DD} = 30V, V_{GS} = 10V,$ $I_D = 20A, R_G = 3\Omega$ | |
| Turn-On Rise Time | tR | _ | 8.8 | _ | ns | | |
| Turn-Off Delay Time | tD(OFF) | _ | 20.8 | — | ns | | |
| Turn-Off Fall Time | tF | _ | 7.4 | — | ns | 7 | |
| Body Diode Reverse Recovery Time | t _{RR} | _ | 34.5 | — | ns | | |
| Body Diode Reverse Recovery Charge | Qrr | _ | 37.5 | — | nC | I _F = 20A, di/dt = 100A/µs | |

5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate. Notes:

Thermal resistance from junction to soldering point (on the exposed drain pad).
 Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.



DMTH6010LPDQ









DMTH6010LPDQ





DMTH6010LPDQ Document number: DS38517 Rev. 5 - 2







Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.







PowerDI5060-8 (Type C)







| PowerDI5060-8 (Type C) | | | | | | |
|------------------------|-------|---------|-------|--|--|--|
| Dim | Min | Max | Тур | | | |
| Α | 0.90 | 1.10 | 1.00 | | | |
| A1 | 0 | 0.05 | 0.02 | | | |
| b | 0.33 | 0.51 | 0.41 | | | |
| b1 | 0.300 | 0.366 | 0.333 | | | |
| b2 | 0.20 | 0.35 | 0.25 | | | |
| С | 0.23 | 0.33 | 0.277 | | | |
| D | 5 | .15 BS0 | 2 | | | |
| D1 | 4.85 | 4.95 | 4.90 | | | |
| D2 | 1.40 | 1.60 | 1.50 | | | |
| D3 | - | - | 3.98 | | | |
| Е | 6 | .15 BS0 | 2 | | | |
| E1 | 5.75 | 5.85 | 5.80 | | | |
| E2 | 3.56 | 3.76 | 3.66 | | | |
| е | 1 | .27BSC |) | | | |
| k | - | - | 1.27 | | | |
| k1 | 0.56 | - | - | | | |
| L | 0.51 | 0.71 | 0.61 | | | |
| La | 0.51 | 0.71 | 0.61 | | | |
| L1 | 0.05 | 0.20 | 0.175 | | | |
| L4 | - | - | 0.125 | | | |
| М | 3.50 | 3.71 | 3.605 | | | |
| x | - | - | 1.400 | | | |
| У | - | - | 1.900 | | | |
| θ | 10° | 12° | 11° | | | |
| θ1 | 6° | 8° | 7° | | | |
| All Dimensions in mm | | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



PowerDI5060-8 (Type C)

| Dimensions | Value (in mm) | | |
|------------|------------------|--|--|
| С | 1.270 | | |
| G | 0.660 | | |
| G1 | 0.820 | | |
| Х | 0.610 | | |
| X1 | 3.910 | | |
| X2 | 1.650 | | |
| X3 | 1.650 | | |
| X4 | 4.420 | | |
| Y | 1.270 | | |
| Y1 | 1.020 | | |
| Y2 | 3.810 | | |
| Y3 | 6.610 | | |



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